TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VHC32F,TC74VHC32FN,TC74VHC32FT,TC74VHC32FK

#### Quad 2-Input OR Gate

The TC74VHC32 is an advanced high speed CMOS 2-INPUT OR GATE fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

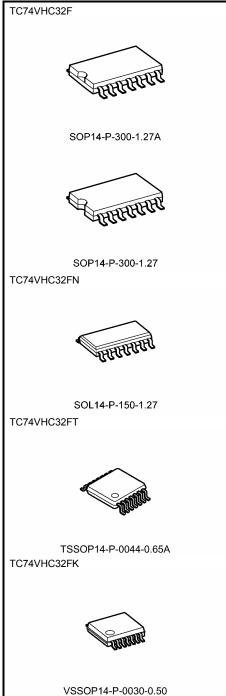
The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **Features**

- High speed:  $t_{pd} = 3.8 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $ICC = 2 \mu A \text{ (max)}$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- · Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC (opr)} = 2 \text{ V to } 5.5 \text{ V}$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS32

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

 SOP14-P-300-1.27A
 : 0.18 g (typ.)

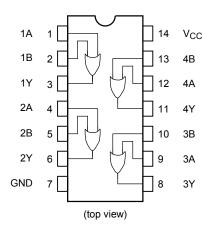
 SOP14-P-300-1.27
 : 0.18 g (typ.)

 SOL14-P-150-1.27
 : 0.12 g (typ.)

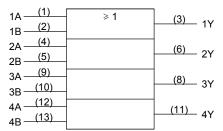
 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

 VSSOP14-P-0030-0.50
 : 0.02 g (typ.)

## **Pin Assignment**



## **IEC Logic Symbol**



### **Truth Table**

Α	В	Υ
Н	Н	Н
L	Н	Н
Н	L	Н
L	L	L

## **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	Гок	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	P <sub>D</sub>	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

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# **Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V	
Input voltage	V <sub>IN</sub>	0 to 5.5	V	
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V	
input rise and fail time	αί/αν	0 to 20 ( $V_{CC} = 5 \pm 0.5 \text{ V}$ )		

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

### **Electrical Characteristics**

### **DC Characteristics**

Characteristics Symbol		Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
			V <sub>C</sub>		Min	Тур.	Max	Min	Max	Offic
High-level input voltage	V <sub>IH</sub>	_		2.0 3.0 to 5.5	1.50 V <sub>CC</sub> × 0.7	-	_ _	1.50 V <sub>CC</sub> × 0.7	-	V
Low-level input voltage	$V_{IL}$	_		2.0 3.0 to 5.5	_ _		0.50 Vcc × 0.3		0.50 V <sub>CC</sub> × 0.3	V
High-level output voltage	V <sub>OH</sub>	VIN = VIH or VIL	I <sub>OH</sub> = -50 μA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	_ _ _	1.9 2.9 4.4	1 1	V
			I <sub>OH</sub> = -4 mA I <sub>OH</sub> = -8 mA	3.0 4.5	2.58 3.94	_	_	2.48 3.80	_	
Low-level output voltage	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0 3.0 4.5	_ _ _	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	V	
			$I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$		_ _		0.36 0.36	1 1	0.44 0.44	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	ı	±1.0	μA
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	2.0	_	20.0	μΑ

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### AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics Symbo	Symbol	Те	st Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	,		V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	
Propagation delay time		_	3.3 ± 0.3	15	_	5.5	7.9	1.0	9.5	- ns
	t <sub>pLH</sub> t <sub>pHL</sub>			50	_	8.0	11.4	1.0	13.0	
			5.0 ± 0.5	15	_	3.8	5.5	1.0	6.5	
				50	_	5.3	7.5	1.0	8.5	
Input capacitance	C <sub>IN</sub>		_		_	4	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub>			(Note)		14	_		_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

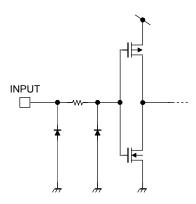
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$ 

#### Noise Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Cumbal	Test Condition	Ta =	Unit		
	Symbol		V <sub>CC</sub> (V)	Тур.	Limit	O III
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.3	-0.8	V
Minimum high level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0	_	1.5	V

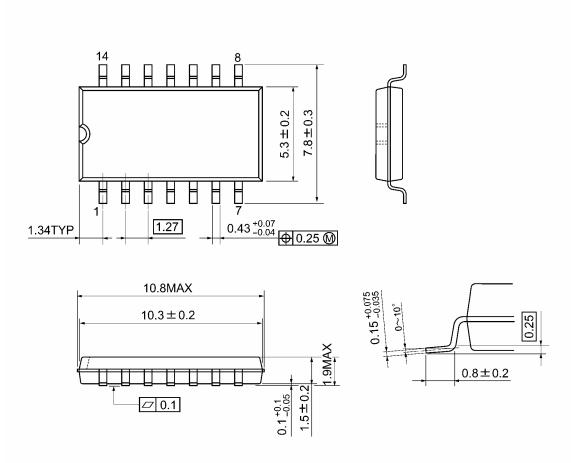
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### **Input Equivalent Circuit**



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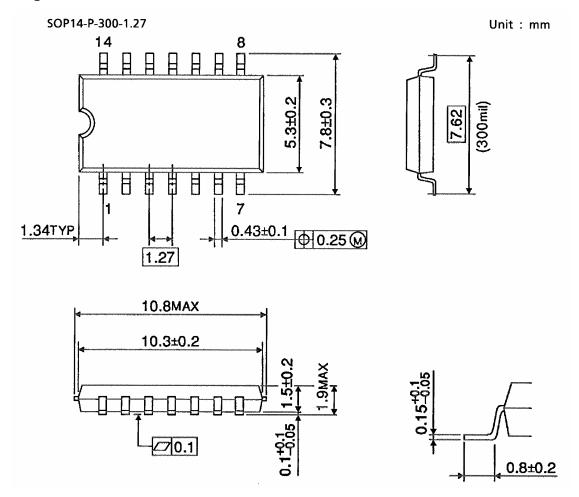
SOP14-P-300-1.27A Unit: mm



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Weight: 0.18 g (typ.)

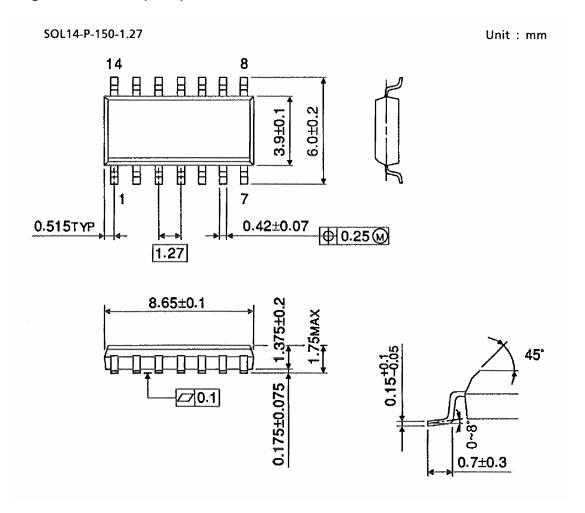




Weight: 0.18 g (typ.)



# **Package Dimensions (Note)**



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Note: This package is not available in Japan.

Weight: 0.12 g (typ.)



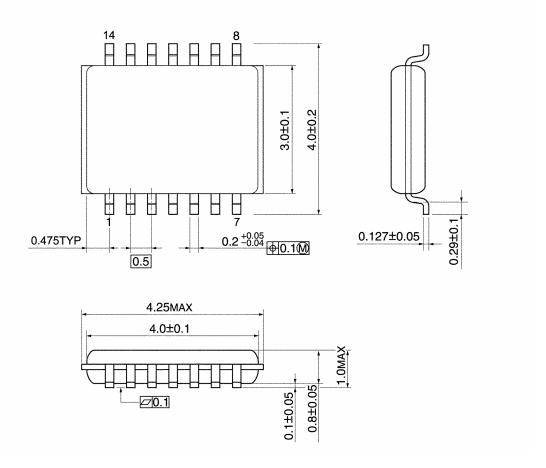
TSSOP14-P-0044-0.65A Unit: mm 6.4±0.2  $0.22^{+0.09}_{-0.06}$ 0.65 0.55TYP **⊕**0.13**M** 5.4MAX 5.0±0.1 0~10 1.0±0.05 0.1±0.05 S Ø.1S (0.5)

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Weight: 0.06 g (typ.)

0.45~0.75

VSSOP14-P-0030-0.50 Unit: mm



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Weight: 0.02 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A VSSOP14-P-0030-0.50

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